SELECTED TOPICS IN
ADVANCED ELECTRONICS

Edited by
Khalid A. S. Al-Khateeb

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CONTENTS

Chapter 1 ......................................................................................................................... 1
WIRELESS CONNECTIVITY OF PC PERIPHERALS USING ULTRAWIDE
BAND (UWB) PULSES
Khalid A. S. Al-Khateeb and Ahmed Ramzi Mohammed

Chapter 2 .......................................................................................................................... 11
VOLTAGE CONTROLLED OSCILLATOR FOR STANDARD GSM USING
MEMS
Khalid A. S. Al-Khateeb

Chapter 3 .......................................................................................................................... 23
MEMS SURFACE ACOUSTIC WAVES OSCILLATOR
Jamilah Karim, Anis Nurashikin Nordin and AHM Zahirul Alam

Chapter 4 .......................................................................................................................... 37
USING MEMS IN CLASS D AMPLIFIERS FOR STANDARD GSM
CARRIER
Khalid A. S. Al-Khateeb

Chapter 5 .......................................................................................................................... 52
MEMS CAPACITIVE ULTRASONIC TRANSDUCERS
Khalid A. S. Al-Khateeb

Chapter 6 .......................................................................................................................... 57
DESIGN OF MEMS CANTILEVER ENERGY HARVESTER
Anis Nurashikin Nordin and Aliza Aini Md Rafib

Chapter 7 .......................................................................................................................... 67
THEORY OF QUANTUM CRYPTOGRAPHY
Ali Sallami and Khalid A. S. Al-Khateeb

Chapter 8 .......................................................................................................................... 77
QUANTUM KEY DISTRIBUTION PROTOCOLS
Ali Sallami and Khalid A. S. Al-Khateeb
Chapter 20......................................................................................................................... 230
AVALANCHE PHOTO DIODES AS SINGLE PHOTON DETECTORS
Khalid A. S. Al-Khateeb

Chapter 21......................................................................................................................... 243
COOLING TECHNIQUES FOR SINGLE PHOTON AVALANCHE DIODE
Nurul Fadzlin Hasbullah, Nurul Izzati Samsuddin and Salmiah Ahmad

Chapter 22......................................................................................................................... 256
SUPERVISORY CONTROL AND DATA AQUISITION SYSTEM (SCADA)
USING MICROCONTROLLER
Khalid A. S. Al-Khateeb and Mohamad Azman Shah

Chapter 23......................................................................................................................... 268
ELECTRONIC REMOTE MONITORING OF INDUSTRIAL SYSTEMS
Khalid A. S. Al-Khateeb

Chapter 24......................................................................................................................... 276
MEDICAL CARE SYSTEM FOR REMOTE MONITORING OF FOETAL ECG
Khalid A. S. Al-Khateeb and Mohammed I. Ibrahimy

Chapter 25......................................................................................................................... 287
INTELLIGENT AUTO TRACKING IN 3D SPACE BY IMAGE PROCESSING
Khalid A. S. Al-Khateeb and Othman O. Khalifa

Chapter 26......................................................................................................................... 300
CIRCUIT DESIGN FOR RADIO FREQUENCY IDENTIFICATION DEVICES (RFID)
Aisyah Jaafer, Nurul Syuhadah Izwar Arfani and Othman O. Khalifa

Chapter 27......................................................................................................................... 309
DYNAMIC TRAFFIC LIGHT SEQUENCE ALGORITHM USING RFID
Khalid A. S. Al-Khateeb, Jaiz A.Y. Johari and Wajdi F. Al-Khateeb

Chapter 28......................................................................................................................... 326
ADVANCED RFID SECURITY FRAMEWORK FOR DYNAMIC TRAFFIC MANAGEMENT
Khalid A. S. Al-Khateeb, Jaiz A. Y. Johari

Chapter 29......................................................................................................................... 337
MODELING CMOS WAFER PRODUCTION LINE USING PROMODEL SOFTWARE
Khalid A. S. Al-Khateeb and Khairul Hakimin B. Zainiddin
Chapter 30......................................................................................................................348
ASIC DESIGN FLOW
Sreedharan Baskara Dass, Aisha_Hassan A. Hashim and Loay Faisal

Chapter 31......................................................................................................................355
ELECTRONIC DESIGN AUTOMATION TOOLS
Sreedharan Baskara Dass, Aisha_Hassan A. Hashim and Loay Faisal

Chapter 32......................................................................................................................365
CIRCUIT DESIGN OF A CLOCK DATA RECOVERY
Z. M. Ashari and Anis N. Nordin

Chapter 33......................................................................................................................376
EFFECTS OF NEUTRON IRRADIATION ON VARIOUS ELECTRONIC DEVICES
Nuurul Iffah Che Omar and Nurul Fadzlin Hasbullah

Chapter 34......................................................................................................................384
NEUTRON SOURCE AND NEUTRON SHIELDING
Nuurul Iffah Che Omar and Nurul Fadzlin Hasbullah

Chapter 35......................................................................................................................390
QUANTUM DOTS AS A SOLUTION TO RADIATION HARDNESS
Nuurul Iffah Che Omar and Nurul Fadzlin Hasbullah
CHAPTER 34

NEUTRON SOURCE AND NEUTRON SHIELDING

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Synopsis
Exposure to neutron radiation may change the doping profile of a diode [1]. This chapter will include information on sources of neutron radiation and its interaction with matter. Neutron sources contained certain percentage of gamma rays that requires to be filtered out to only obtain neutron component from the neutron source or reactor. Neutron source such as $^{252}$Cf can generate fluences up to $10^{13} \text{n/cm}^2$ and a reactor is needed to achieve higher neutron fluences [2]. Several filtering techniques are also discussed.

1. Sources of Neutron Radiation
Neutron was first discovered in 1932 by Chadwick [3]. Neutron radiation is a non-ionizing radiation where it does not ionize atoms in the same way charged particles such as protons and electrons because neutrons have no charge. However, Neutron irradiation causes indirect ionisation to occur as high energy particles collide with the atomic structure removing or adding an electron to an atom. Neutrons are mainly produced by reaction with alpha particles or photon, spontaneous and induced nuclear fission. Spontaneous fission is a quantum mechanical process which involves the penetration of a potential barrier. The height of the barrier and fission rate is very sensitive to atomic number, Z and atomic mass, A. The fission rates are different for different Z-A isotopes. Odd-even isotopes have fission rates typically $10^3$ lower than the rate for even-even isotopes. Examples of even-even isotopes with high spontaneous fission yields are $^{238}$U, $^{240}$Pu, $^{244}$Cm and $^{252}$Cf [4]. $^{252}$Cf isotope is the most commonly used neutron source as it is portable and suitable for laboratory work. The overall characteristics of $^{252}$Cf are shown in the table below.